

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1	"20050174835"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:06
S2	28	Unity-Semiconductor\$8.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:02
S3	2	"20050101086"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:01
S4	2	"20040160798"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:01
S5	65	"6,204,139" "6,531,371"	US-PGPUB	OR	ON	2005/08/21 17:01
S6	39	"6,204,139" "6,531,371"	USPAT	OR	ON	2005/08/21 17:01
S7	33	10/330,512 10/680,508	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:01
S8	2	"20050013172"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:01
S9	3	"6909632"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:01
S10	7	"6909632" "6834008"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:01
S11	3	Unity-Semiconductor\$8.as.	US-PGPUB	OR	ON	2005/08/21 17:03
S13	44824	memory adj array	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:06
S14	58	S13 and two-terminal adj memory	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:27
S15	13	S14 and plug	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:08

S17	10	S14 and multi-resistive near3 element	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:10
S18	0	"10680508"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:10
S19	7	"10/680508"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:18
S21	7	S19 and (second write voltage)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:21
S22	31	10/330,512	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:20
S23	7	S19 and (high resistive state)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:21
S24	7	S19 and (low resistive state)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:22
S25	7	S19 and change	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:57
S26	1	"20050180242"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/21 17:57
S27	31	Unity-Semiconductor\$8.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/20 17:19
S28	2	"20050174835"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/20 17:45
S29	2	"20050101086"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:14

S30	4	"6856536"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/20 17:49
S31	15	10/612,191	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/20 17:49
S32	8	"10/680508"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/20 19:28
S33	8	S32 and (first write voltage)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/20 19:28
S34	2	"20040160812"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:19
S35	2	"20040160804"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:20
S36	7	"6859382"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:20
S38	2	"20050195632"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:21
S39	2	"20050174835"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 05:53
S40	2	"20050101086"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:22
S41	2	"20040160817"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:22
S42	12	S34 or S35 or S38 or S39 or S40 or S41	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:41
S43	6	S34 or S35 or S38 or S39 or S40 or S41	US-PGPUB	OR	ON	2005/11/28 03:23

S44	6	S34 or S35 or S38 or S39 or S40 or S41	DERWENT	OR	ON	2005/11/28 03:23
S45	46309	memory adj array	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:25
S46	6	S45 and two-terminal near3 plug	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:30
S47	73	S45 and two-terminal near2 memory	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:33
S48	11	S47 and conductive near2 element	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:42
S49	2	S48 and reactive near3 metal	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:28
S50	14	S47 and multi\$resistive near3 state	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:29
S51	33	S45 and multi\$resistive near3 state same element	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:31
S52	38	S45 and two-terminal near2 memory	USPAT	OR	ON	2005/11/28 03:33
S53	12	S47 and reactive	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:35
S54	4	S47 and reactive adj metal	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:40
S56	1	"20050243595"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:41
S57	12	S47 and apply\$5 near3 writ\$5 adj voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:42

S58	0	S47 and apply\$5 near3 first near2 writ\$5 adj voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:43
S59	1	S47 and appl\$7 near3 first near2 writ\$5 adj voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 03:44
S61	1	S47 and appl\$7 near3 first near4 writ\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 04:37
S62	73	"6473332"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 04:38
S63	2	("6473332").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/11/28 04:44
S64	2	("6473332").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/11/28 04:58
S65	2	("20050101086").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/11/28 04:59
S66	127	"20050101086" "6204139" "6531371"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 05:00
S67	4	((("6204139") or ("6531371"))).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/11/28 05:02
S69	5	10/605963	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 05:19
S70	2	"20040160819"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 05:21
S71	3	"6917539"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 05:28

S72	2	"20040160804"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 05:31
S73	9	"6856536" "6859382"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/28 05:31